

Features:

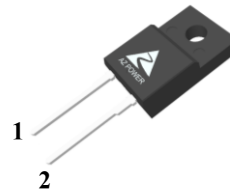
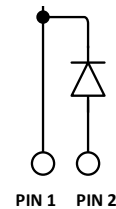
- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent

Switching

Benefits:

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
V_{RRM}	650	V
I_F ($T_c = 118^\circ\text{C}$)	15	A
Q_C	32	nC

Outline

TO-220-2FP
Circuit

Applications:

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
V_{RRM}	Repetitive Peak Reverse	650	V	$T_J = 25^\circ\text{C}$
V_{RSM}	Surge Peak Reverse Voltage	650	V	$T_J = 25^\circ\text{C}$
I_F	Continuous Forward Current	28	A	$T_C = 25^\circ\text{C}$
		21.5		$T_C = 75^\circ\text{C}$
		15		$T_C = 118^\circ\text{C}$
I_{FRM}	Repetitive Peak Forward Surge Current	88	A	$T_C = 25^\circ\text{C}$, $T_p = 10\text{ms}$, Half Sine Wave
		79		$T_c = 110^\circ\text{C}$, $T_p = 10\text{ms}$, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	119	A	$T_C = 25^\circ\text{C}$, $T_p = 10\text{ms}$, Half Sine Wave
		107		$T_c = 110^\circ\text{C}$, $T_p = 10\text{ms}$, Half Sine Wave
P_D	Power Dissipation	71	W	$T_C = 25^\circ\text{C}$
		31		$T_c = 110^\circ\text{C}$
$T_{J,max}$	Operating Junction Temperature	175	$^\circ\text{C}$	
T_{stg}	Storage Temperature Range	-55 to 175	$^\circ\text{C}$	

Thermal characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit
R_{thJC}	Thermal resistance		2.1		°C/W

Electrical Characteristics

Symbol	Parameter	Value			Unit	Test Conditions
		Min.	Typ.	Max.		
V_{DC}	DC Blocking Voltage	650			V	$I_R = 100\mu A$, $T_J = 25^\circ C$
V_F	Forward Voltage		1.55 1.9	1.8 2.2	V	$I_F = 15A$, $T_J = 25^\circ C$ $I_F = 15A$, $T_J = 175^\circ C$
I_R	Reverse Current		5 20	100 250	μA	$V_R = 650V$, $T_J = 25^\circ C$ $V_R = 650V$, $T_J = 175^\circ C$
Q_C	Total Capacitive Charge		32		nC	$I_F = 15A$, $dI/dt = 350A/\mu s$ $T_J = 25^\circ C$, $V_R = 400V$
C	Total Capacitance		619 96 94		pF	$V_R = 1V$, $T_J = 25^\circ C$, $f = 1\text{ MHz}$ $V_R = 200V$, $T_J = 25^\circ C$, $f = 1\text{ MHz}$ $V_R = 400V$, $T_J = 25^\circ C$, $f = 1\text{ MHz}$

Typical Performance

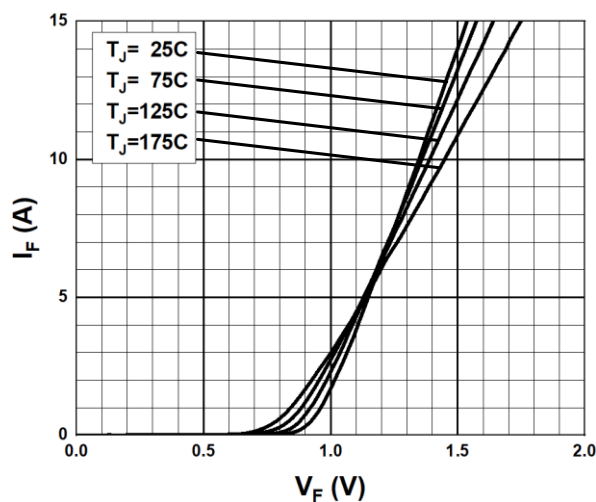


Fig. 1 Forward Characteristics

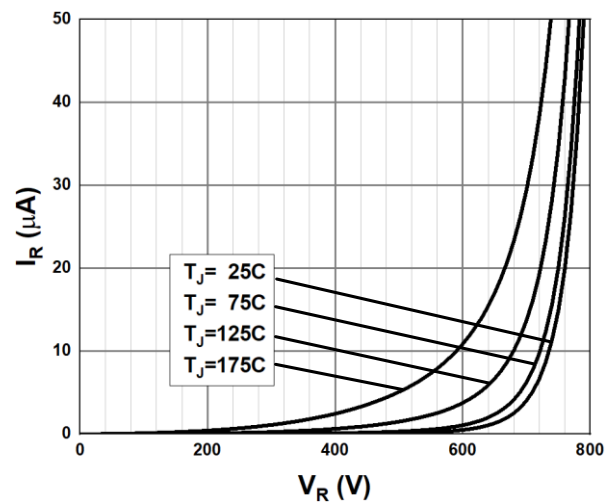


Fig. 2 Reverse Characteristics

Typical Performance

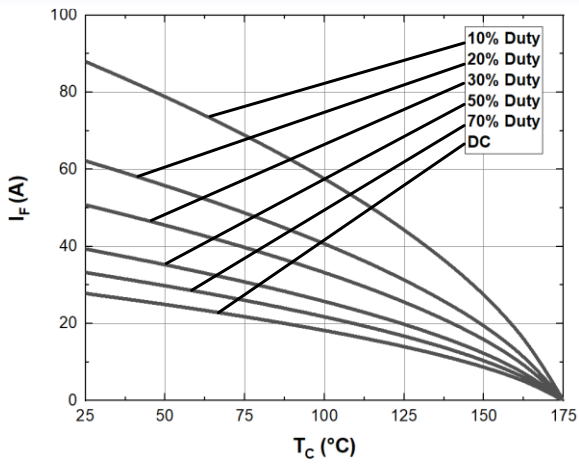


Fig. 3 Current Derating

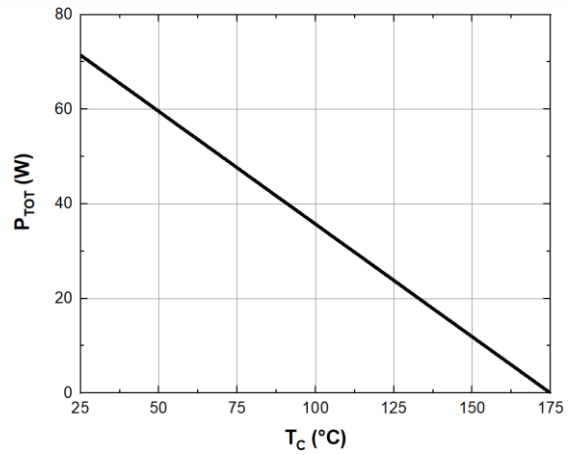


Fig. 4 Power Derating

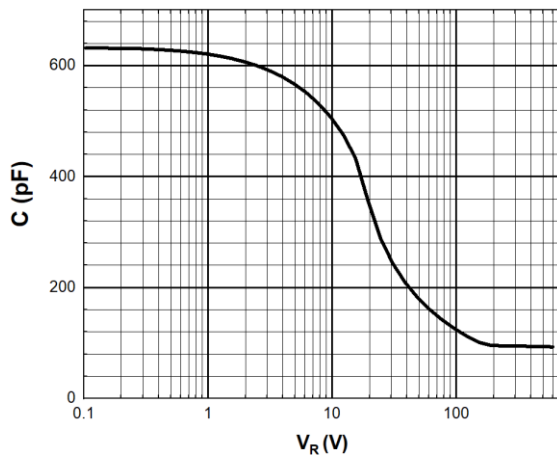


Fig. 5 Capacitance vs. Reverse Voltage

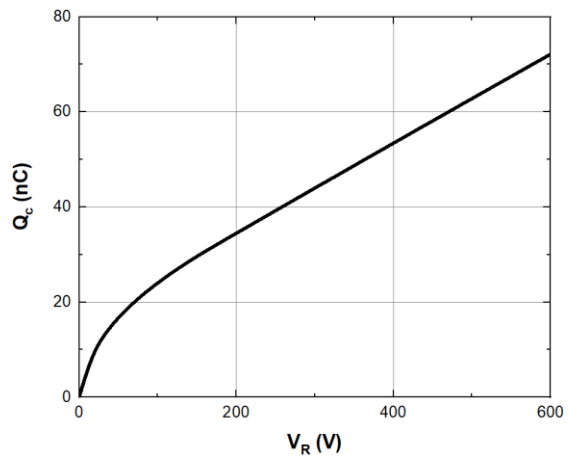


Fig. 6 Recovery Charge vs. Reverse Voltage

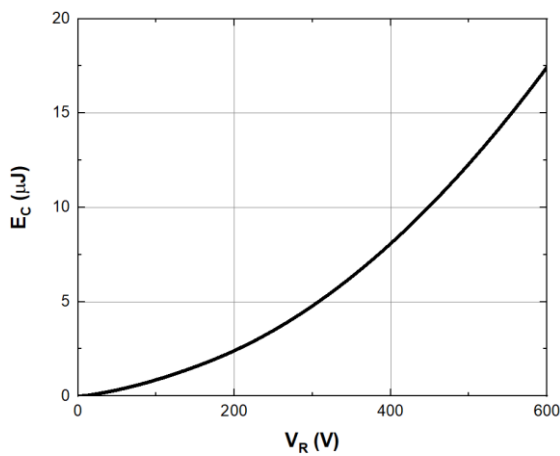


Fig. 7 Capacitance stored Energy

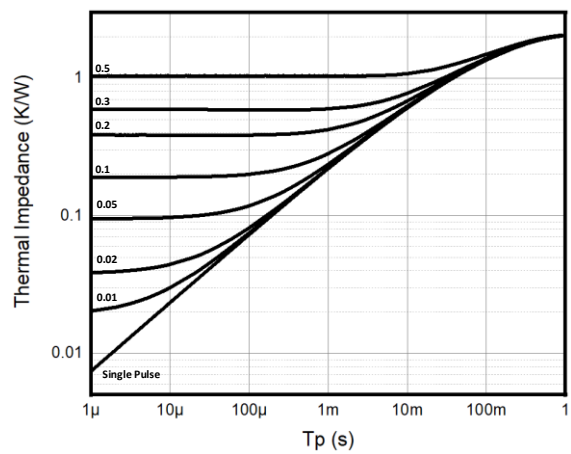
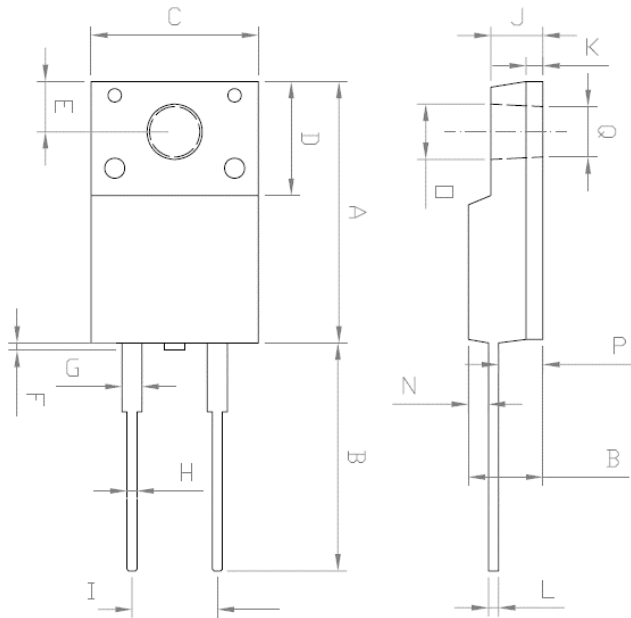


Fig. 7 Thermal Impedance

Package TO-220-2FP (Unit: mm)



REF.DIM	DATA BOOK mm		
	NOR	MIN	MAX
A	15.6	14.8	16.1
B	13	12.65	13.8
C	10	9.85	10.36
D	6.5	4.6	6.8
E	3.0	2.55	3.5
F			1
G	1.2	1	1.45
H	0.6	0.3	0.9
I	5.1	4.8	5.4
J	3.1	2.34	3.3
K	1.0	0.55	1.3
L	0.6	0.36	0.8
M	4.45	4.2	4.9
N	1.2	1.1	1.8
O	3.3	2.9	3.5
P	2.6	2.5	3.15
Q	3	2.9	3.5

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